ALTERNATIVE TO PTO/SB/08A/B

					(Based on PTO 08-08 version	
Cut	stitute for form 1449/PT0	,		Complete if Known		
300	Substitute for form 144arr 10			Application Number	10/537,804	
l in	IFORMATIC	N DIS	CLOSURE	Filing Date	June 7, 2005	
	TATEMENT			First Named Inventor	Robert DWILINSKI	
ľ	.,	J. 71.	Liorari	Art Unit	1792	
	(Use as many sheets as necessary)			Examiner Name	F. C. Hiteshew	
Sheet	1	of	2	Attomey Docket Number	204552035400	

U.S. PATENT DOCUMENTS							
Examiner Initials*	Cite No.1	Document Number Number-Kind Code ² (If known)	Publication Date MM-DD-YYYY		Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear		
	1.	US-6,153,010-A	11-28-2000	Kiyoku et al.			
	2.	US-2002/0011599-A1	01-31-2002	Motoki et al.			

		FOREI	GN PATENT	DOCUMENTS		
Examiner	Cite No.	Foreign Patent Document	Publication Date	Name of Patentee or	Pages, Columns, Lines, Where Relevant Passages Or Relevant Figures Appear	
Initials*		Country Code ³ -Number ⁴ -Kind Code ⁵ (if known)	MM-DD-YYYY	Applicant of Cited Document		T°
	3.	WO-98/47170-A	10-22-1998	Nichia Chemical Industries Ltd.	Translation of abstract and corresponds to US-6,153,010 listed above	
	4.	JP-2000-44400-A	02-15-2000	Sumitomo Electric Industries	Translation of abstract and corresponds to US-2002/0011599 listed above	
	5.	WO-01/68955-A1	09-20-2001	Advanced Technology Materials, Inc.		П
	6.	JP-2003-527296-A	09-16-2003	Advanced Technology Materials, Inc.	Corresponds to WO-01/68955	

*EXAMINES: Initial information considered, whether or not classics is nonformance with IMEPS 000. One lies through classics if not no conceived. Including classics of the contractions that a page and . *Nge-thern urique classics recipient marking classics. See prince (Contraction See) and Contraction of the Contract

		NON PATENT LITERATURE DOCUMENTS	
Examiner Initials	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, cit) and/or country where published.	T ²
	7.	Japanese Notification of Provision of Relevant Information on Prior Arts, mailed December 24,2008, directed to Japanese Patent Application No. 2004-558483; 14 pages	1
	8.	Kato, H. et al. (May 28, 1988)."MOVPE Growth of GaN on off-angle sapphire substrate", IEICE Technical Report. The Institute of Electronics, Information and Communication Engineers of Japan. Tokyo, Japan. 88(61):9 pages	1
	9.	Sakai, A. et al., (October 20, 1997). "Defect structure in selectively grown GaN films with low threading dislocation density." Appl. Phys. Lett. 71(16):2259-2261	
	10.	Dwilinski, R. et al., U.S. Office Action, mailed September 7, 2006, directed to a related U.S. Patent Application No. 10/479,857; 18 pages	
	11.	Dwilinski, R. et al., U.S. Office Action, mailed March 21, 2007, directed to a related U.S. Patent Application No. 10/479,857; 15 pages	
	12.	Dwillinski, R. et al., U.S. Office Action, mailed October 17, 2007 directed to a related U.S. Patent Application No. 10/479,857; 12 pages	

Receipt date: 06/16/2009

ALTERNATIVE TO PTO/SB/08A/B

Substitute for form 1449/PTO				Complete if Known		
Substitute for form 1449/F10				Application Number	10/537,804	
INF	ORMATI	ON DIS	CLOSURE	Filing Date	June 7, 2005	
			PPLICANT	First Named Inventor	Robert DWILINSKI	
OTATEMENT BY ALT EIGANT				Art Unit	1792	
	(Use as many sheets as necessary)			Examiner Name	F. C. Hiteshew	
Sheet	2	of	2	Attorney Docket Number	204552035400	

	Dwillinski, R. et al., U.S. Office Action, mailed November 14, 2006, directed to a related U.S.		l
	Patent Application No. 10/519,141; 5 pages		ı
	Dwilinski, R. et al., U.S. Office Action, mailed June 4, 2007, directed to a related U.S. Patent	\Box	ı
	Application No. 10/519,141; 5 pages		ı

Examiner	/Matthew Song/	Date	
Signature	/wattrew sorig/	Considered	08/11/2010

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹Applicant's unique citation designation number (optional). ²Applicant is to place a check mark here if English language Translation is attached.